

### **T2035H Series**

## Snubberless™ high temperature 20 A Triacs

#### **Main features**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	20	Α
V <sub>DRM</sub> /V <sub>RRM</sub>	600	V
I <sub>GT (Q1)</sub>	35	mA
T <sub>j MAX</sub>	150	°C

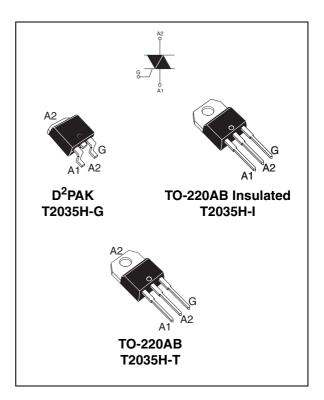
#### **Description**

Specifically designed to operate at 150° C, the new 20 A T2035H Triacs provide an enhanced performance in terms of power loss and thermal dissipation. This facilitates the optimization of heatsink dimensioning, leading to improved space and cost effectiveness when compared to electromechanical solutions.

Based on ST Snubberless<sup>TM</sup> technology, the T2035H series offers high commutation switching capabilities and high noise immunity levels on the full range of  $T_i$ .

The T2035H series facilitates the optimization of the control of universal motors and inductive loads found in appliances such as vacuum cleaners, and washing machines.

The T2035H Triacs are also suitable for use in high temperature environment found in hot appliances such as cookers, ovens, hobs, electric heaters, and coffee machines.



#### Order code

Part number	Marking
T2035H-600G	T2035H-600G
T2035H-600G-TR	T2035H-600G
T2035H-600TRG	T2035H-600T
T2035H-600IRG	T2035H-600I

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Characteristics T2035H Series

### 1 Characteristics

Table 1. Absolute maximum ratings

Symbol	Parameter				Unit
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave)	D <sup>2</sup> PAK TO-220AB	T <sub>c</sub> = 127° C	20	А
		TO-220AB Ins	T <sub>c</sub> = 105° C		
1 .	Non repetitive surge peak on-state current	F = 60 Hz	t = 16.7 ms	210	Α
I <sub>TSM</sub>	(full cycle sine wave, T <sub>j</sub> initial = 25° C)	F = 50 Hz	t = 20 ms	200	Α .
l²t	I <sup>2</sup> t Value for fusing tp = 10 r		0 ms	283	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current $I_G = 2xI_{GT}$ , tr $\leq$ 100 ns		T <sub>j</sub> = 125° C	50	A/µs
V <sub>DSM</sub> /V <sub>RSM</sub>	Non repetitive surge peak off state voltage $T_j = 25^{\circ}$		T <sub>j</sub> = 25° C	700	V
I <sub>GM</sub>	Peak gate current $t_p = 20 \mu s$		T <sub>j</sub> = 150° C	4	Α
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 150^{\circ} \text{ C}$			1	W
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range			-40 to +150 -30 to +150	°C
T <sub>I</sub>	Maximum leads soldering temperature during 10 s			260	°C

Table 2. Electrical characteristics ( $T_j = 25^{\circ}$  C, unless otherwise specified)

Symbol	Test conditions Quadrant			Value	Unit
I <sub>GT</sub> <sup>(1)</sup>	$V_{D} = 12 \text{ V}, R_{L} = 33 \Omega$	1 - 11 - 111	MAX	35	mA
V <sub>GT</sub>	VD = 12 V, nL = 33 32	1 - 11 - 111	MAX	1.3	V
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega, T_j = 150^{\circ} \text{ C}$ I - II - III		MIN	0.15	V
I <sub>H</sub> <sup>(2)</sup>	I <sub>T</sub> = 100 mA		MAX	35	mA
	_12v	I - III	MAX	50	mA
IL	$I_{G} = 1.2 \times I_{GT}$	II	IVIAA	80	
dV/dt (2)	V <sub>D</sub> = 67% V <sub>DRM</sub> , gate open, T <sub>j</sub> = 150° C		MIN	300	V/µs
(dl/dt)c (2)	Without snubber, $T_j = 150^{\circ} C$		MIN	8.9	A/ms

<sup>1.</sup> minimum  $I_{\mbox{\scriptsize GT}}$  is guaranteed at 5% of  $I_{\mbox{\scriptsize GT}}$  max

<sup>2.</sup> for both polarities of A2 referenced to A1

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Table 3. Static electrical characteristics

Symbol	Test conditions			Value	Unit
V <sub>TM</sub> <sup>(1)</sup>	I <sub>TM</sub> = 28 A, t <sub>p</sub> = 380 μs	Tj = 25° C	MAX	1.5	V
V <sub>TO</sub> <sup>(1)</sup>		Tj = 150° C	MAX	0.80	V
R <sub>D</sub> <sup>(1)</sup>		Tj = 150° C	MAX	21	mΩ
	V - V	Tj = 25° C		5	μΑ
I <sub>DRM</sub> VDRM = VRRM	$V_{DRM} = V_{RRM}$	Tj = 150° C	MAX	7.4	mA
'KKM	V <sub>D</sub> /V <sub>R</sub> = 400 V (at peak mains voltage)	Tj = 150° C		4.8	IIIA

<sup>1.</sup> for both polarities of A2 referenced to A1

Table 4. Thermal resistance

Symbol	Parameter			Value	Unit
R <sub>th (j-c)</sub>	Junction to case for full (AC)		D <sup>2</sup> PAK TO-220AB	1	
() =/			TO-220AB Ins	1.9	°C/W
	S = 1 cm <sup>2</sup>		D <sup>2</sup> PAK	45	C/VV
R <sub>th (j-a)</sub>	Junction to ambient		TO-220AB TO-220AB Ins	60	

Figure 1. Maximum power dissipation vs RMS on-state current (full cycle)

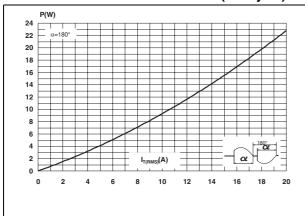
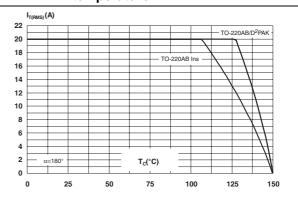


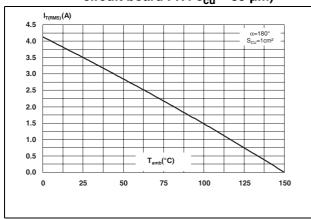
Figure 2. RMS on-state current versus case temperature



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Figure 3. RMS on-state current vs ambient temperature (epoxy printed circuit board FR4  $e_{cu}$  = 35  $\mu$ m)

Figure 4. Relative variation of thermal impedance vs pulse duration



1.E-02

1.E-03

1.E-03

1.E-02

1.E-01

1.E-01

1.E-03

1.E-03

1.E-02

1.E-01

1.E-01

1.E-03

1.E-03

1.E-03

1.E-03

1.E-03

1.E-03

1.E-03

Figure 5. On-state characteristics (maximum values)

100 I<sub>TM</sub>(A)

100 T<sub>j=150°C</sub>

T<sub>j=25°C</sub>

T<sub>j</sub>

Figure 6. Surge peak on-state current vs number of cycles

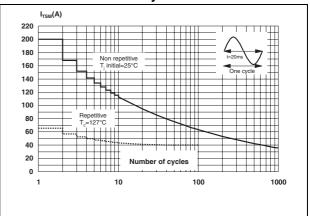
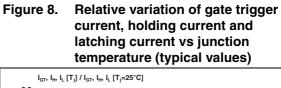
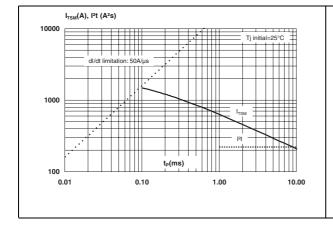
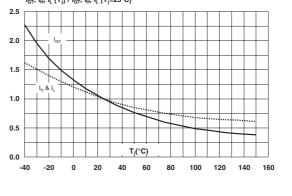


Figure 7. Non repetitive surge peak on-state current (sinusoidal pulse width tp<10 ms) and value of I<sup>2</sup>t







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T2035H Series **Characteristics** 

Figure 9. Relative variation of critical rate of decrease of main current (di/dt)c vs reapplied (dV/dt)c

(dl/dt)<sub>c</sub> [ (dV/dt)<sub>c</sub> ] / Specified (dl/dt)<sub>c</sub>

2.0 1.8

1.6

1.4 1.2

1.0 0.8

0.6

0.4 0.2

0.0

0.1

7 6 5 3 2

Figure 10. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature

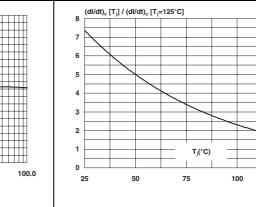


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

10.0

1.0

1.E+01 1.E+00 1.E-01 1.E-02 1.E-03 1.E-04 50 75 100 125 150

Figure 12. Acceptable repetitive peak off-state voltage versus case-ambient thermal resistance

125

150

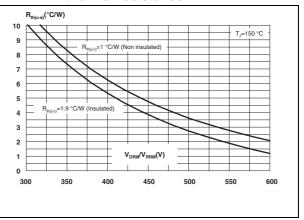
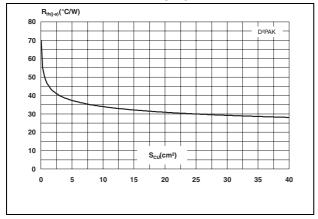
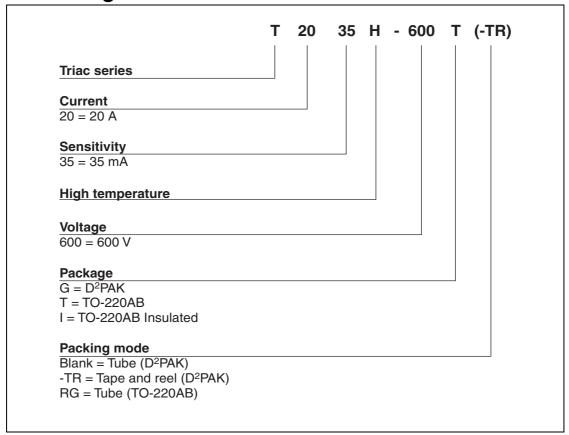


Figure 13. D<sup>2</sup>PAK junction to ambient thermal resistance versus copper surface under tab (PCB FR4, copper thickness 35 µm)



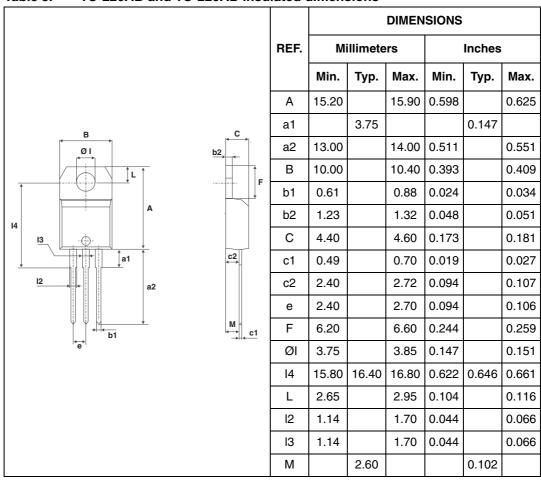
## 2 Ordering information scheme



T2035H Series Package information

## 3 Package information

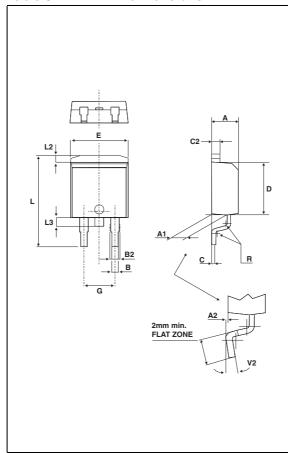
Table 5. TO-220AB and TO-220AB Insulated dimensions



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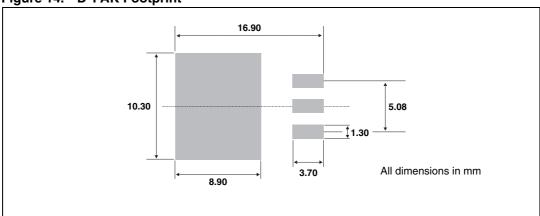
Package information T2035H Series

Table 6. D<sup>2</sup>PAK dimensions



	DIMENSIONS				
REF.	Millimeters		Inches		
	Min.	Min. Max.		Max.	
Α	4.40	4.60	0.173	0.181	
A1	2.49	2.69	0.098	0.106	
A2	0.03	0.23	0.001	0.009	
В	0.70	0.93	0.027	0.037	
B2	1.14	1.70	0.045	0.067	
С	0.45	0.60	0.017	0.024	
C2	1.23	1.36	0.048	0.054	
D	8.95	9.35	0.352	0.368	
Е	10.00	10.40	0.393	0.409	
G	4.88	5.28	0.192	0.208	
L	15.00	15.85	0.590	0.624	
L2	1.27	1.40	0.050	0.055	
L3	1.40	1.75	0.055	0.069	
М	2.40	3.20	0.094	0.126	
R	0.40 typ.		0.016	6 typ.	
V2	0°	8°	0°	8°	

Figure 14. D<sup>2</sup>PAK Footprint



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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# 4 Ordering information

Part number	Marking	Package	Weight	Base Qty	Packing mode
T2035H-600G	T2035H-600G	D <sup>2</sup> PAK	1.5 g	50	Tube
T2035H-600G-TR	T2035H-600G	D <sup>2</sup> PAK	1.5 g	1000	Tape and Reel
T2035H-600TRG	T2035H-600T	TO-220AB	2.3 g	50	Tube
T2035H-600IRG	T2035H-600I	TO-220ABIns	2.3 g	50	Tube

# 5 Revision history

Date	Revision	Changes	
13-Jul-2006	1	Initial release.	
7-Sep-2006	2	Added TO-220AB Insulated package.	

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